

Spezifikationen	
Artikelnummer	MJD32CTM
Hersteller	FDK America
Beschreibung	TRANS PNP 100V 3A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	2894 pcs Stock
Spannung - Kollektor-Emitter-Durchbruch (max)	3A
Spannung - Durchschlag	D-Pak
VCE Sättigung (Max) @ Ib, Ic	100V
Serie	-
RoHS Status	Digi-Reel®
Widerstand - Base (R1) (Ohm)	3MHz
Leistung - max	1.56W
Polarisation	TO-252-3, DPak (2 Leads + Tab), SC-63
Andere Namen	MJD32CTMDKR
Betriebstemperatur	150°C (TJ)
Befestigungsart	Surface Mount
Feuchtigkeitsempfindlichkeitsstufe (MSL)	1 (Unlimited)
Hersteller Standard Vorlaufzeit	6 Weeks
Hersteller-Teilenummer	MJD32CTM
Frequenz - Übergang	10 @ 3A, 4V
Expanded Beschreibung	Bipolar (BJT) Transistor PNP 100V 3A 3MHz 1.56W
Beschreibung	TRANS PNP 100V 3A DPAK
DC Stromgewinn (HFE) (Min) @ Ic, VCE	50µA
Strom - Collector Cutoff (Max)	1.2V @ 375mA, 3A
Strom - Kollektor (Ic) (max)	PNP

sein:

MJD32CTF_NBDD002
AMI Semiconductor / ON
Semiconductor
TRANS PNP 100V 3A DPAK

sein:  MJD32CTF_NBDD002 AMI Semiconductor / ON Semiconductor TRANS PNP 100V 3A DPAK	 MJD32CUQ-13 Diodes Incorporated PWR MID PERF TRANSISTOR TO252	 MJD32CTM AMI Semiconductor / ON Semiconductor TRANS PNP 100V 3A DPAK	 MJD32CTF_NBDD002 Fairchild/ON Semiconductor TRANS PNP 100V 3A DPAK
 MJD32CTF IC FAIRCHILD FAIRCHILD 252	 MJD32RLG ON Semiconductor TRANS PNP 40V 3A DPAK	 MJD32T4 ON MJD32T4 ON	 MJD32RL TO-252 MJD32RL TO-252

Schlüsselwort	MJD32CTM Datenblatt	MJD32CTM-Datenblätter	MJD32CTM PDF	FDK America MJD32CTM
MJD32CTM Electronic	MJD32CTM-Komponenten	MJD32CTM-Verteiler	MJD32CTM-Bild	MJD32CTM-Teil
MJD32CTM Preis	MJD32CTM Hersteller	MJD32CTM Bild	MJD32CTM Aktie	MJD32CTM Inventar
MJD32CTM Neu	MJD32CTM Original	MJD32CTM garantiert	MJD32CTM RFQ	MJD32CTM Online bestellen